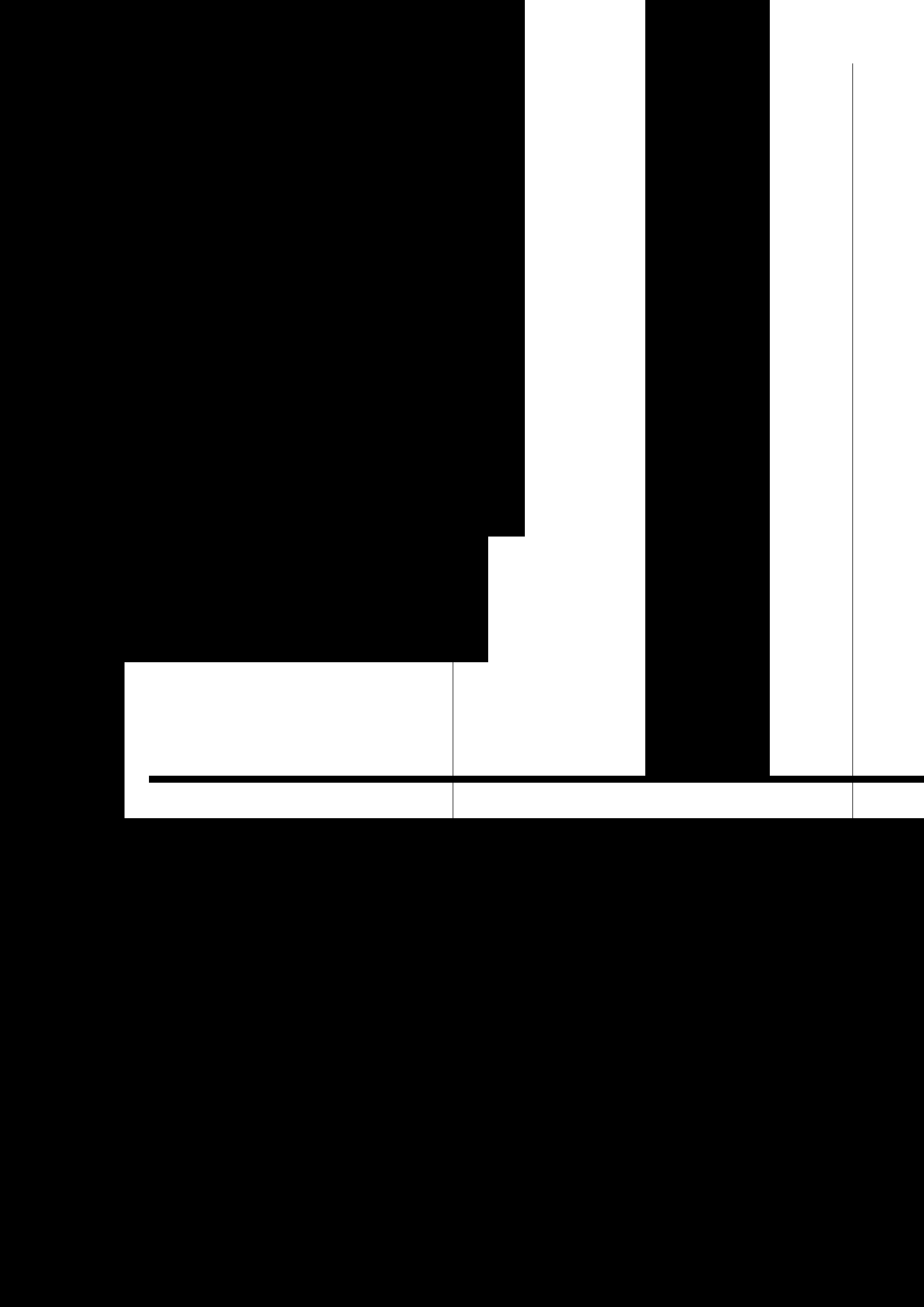


Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	4.5	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D=12V R_L=33Ω	- -	MAX.	5	mA
				10	
V_{GT}		ALL	MAX.	1	V
V_{GD}	V_D=V_{DRM} T_j=125 R_L=3.3kΩ	ALL	MIN.	0.2	V
I_L	I_G=1.2I_{GT}	- -	MAX.	15	mA
				20	
I_H	I_T=500mA		MAX.	10	mA
dV/dt	V_D=400V Gate Open T_j=125		MIN.	50	V/μs
(dV/dt)c	(dI/dt)c=7.2A/ms, T_j=110		MIN.	2	V/μs
t_{on}	I_G=20mA I_A=200mA I_R=20mA T_j=25		TYP.	3	μs
t_{off}				50	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM}=20A t_p=380μs	T_j=25	1.5	V
V_{TO}	Threshold voltage	T_j=125	0.75	V
R_D	Dynamic resistance	T_j=125	27	mΩ
I_{DRM}	V_D=V_{DRM} V_R=V_{RRM}	T_j=25	5	μA
I_{RRM}		T_j=125	0.4	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	2.3	/W
$R_{th(j-a)}$	junction to ambient (AC)	60	/W

ORDERING INFORMATION

J	ST	139	A	-600	D
JieJie Microelectronics Co., Ltd.	Triacs	$I_{T(RMS)}$:16A	A:TO-220A(Ins)	600:V_{DRM} /V_{RRM} 600V	D:I_{GT1-3} 5mA I_{GT4} 10mA

MARKING

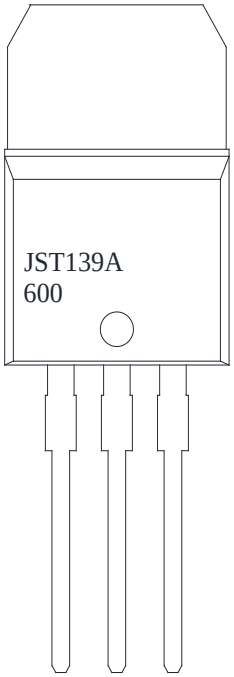


FIG.1: Maximum power dissipation versus RMS on-state current

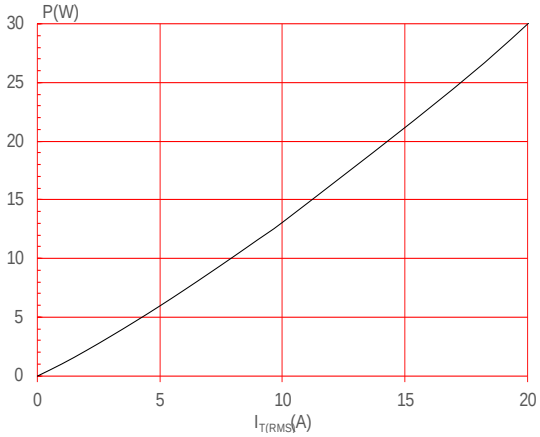
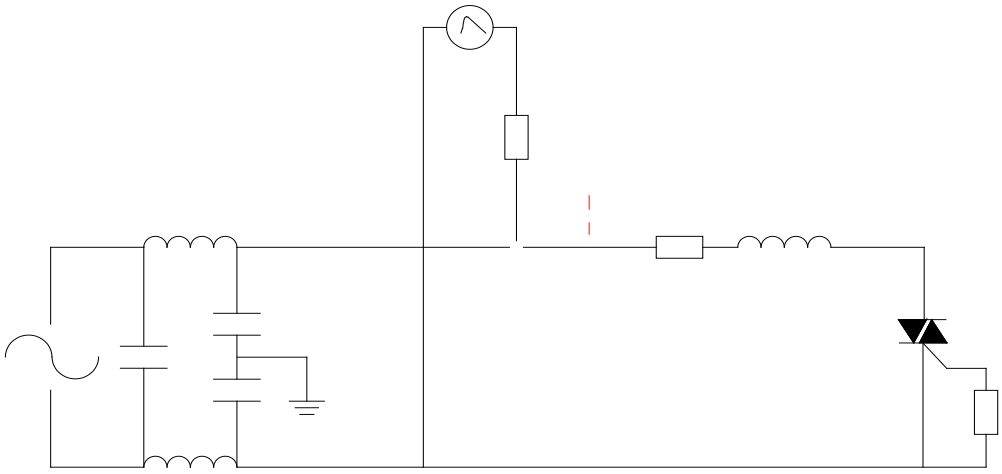


FIG.2: RMS on-state current versus case temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		- -				
JST139A-600D	600	5	10	TO-220A(Ins)	50	Tube